

## Thin type COBP Photo Diode

### ■FEATURES

- Leadless surface mount type: 1.2 X 1.7 X 0.5mm
- Sensitive peak wavelength: 850nm
- Corresponding to infrared light from the blue-violet light
- Active area: 0.7mm X 0.7mm
- Pb free solder re-flowing permitted: 260°C, 2times
- Pb free, Halogen free
- Conformity to RoHS directive

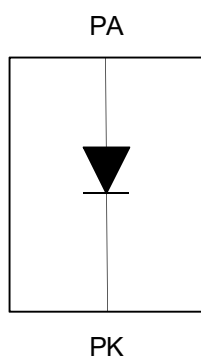
### ■GENERAL DESCRIPTION

The NJL6193R-3 is the photodiode sensor capable of detecting light in a wide wavelength range of up to infrared light from the blue-violet light.  
A thin and small package of COBP is adopted, and providing high efficient space-saving.

### ■APPLICATION

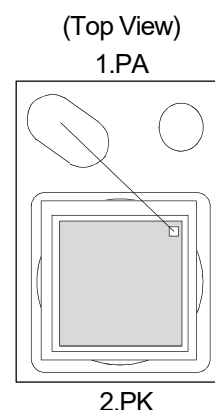
- Heart rate monitoring of Wearable Devices (In-Ear phone, Smart watch, Fitness Tracker etc.)
- Mobile Devices
- Optical switch

### ■EQUIVALENT CIRCUIT・BLOCK DIAGRAM



### ■PIN CONFIGURATION

| PIN NO. | SYMBOL | DESCRIPTION |
|---------|--------|-------------|
| 1       | PA     | Anode       |
| 2       | PK     | Cathode     |



### ■ORDERING INFORMATION

| PART NUMBER | PACKAGE OUTLINE | RoHS | HALOGEN-FREE | TERMINAL FINISH | MARKING    | WEIGHT (mg) | MOQ(pcs) |
|-------------|-----------------|------|--------------|-----------------|------------|-------------|----------|
| NJL6193R-3  | COBP            | ✓    | ✓            | Au              | No marking | 2.1         | 3,000    |

## ■ABSOLUTE MAXIMUM RATINGS

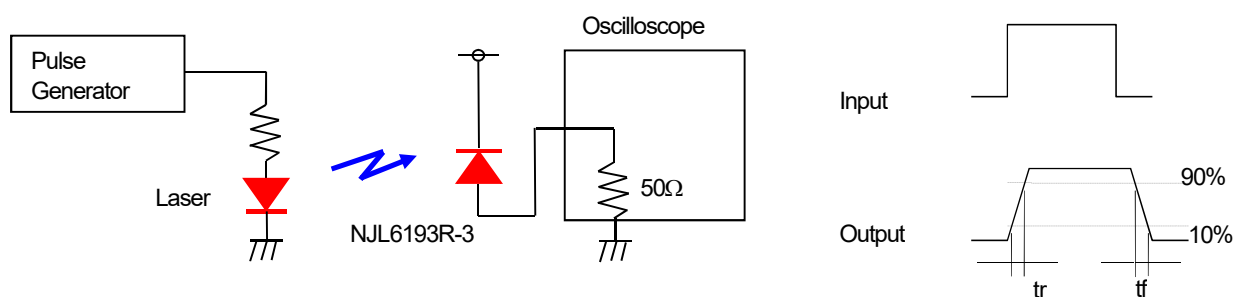
| PARAMETER                    | SYMBOL    | RATINGS     | UNIT |
|------------------------------|-----------|-------------|------|
| Reverse Voltage              | $V_R$     | 35          | V    |
| Operating Temperature Range  | $T_{opr}$ | -30 to +85  | °C   |
| Storage Temperature Range    | $T_{stg}$ | -40 to +100 | °C   |
| Reflow Soldering Temperature | $T_{sol}$ | 260         | °C   |

## ■ELECTRICAL CHARACTERISTICS ( $T_a=25^\circ\text{C}$ )

| PARAMETER            | SYMBOL      | TEST CONDITION                                                                         | MIN. | TYP. | MAX. | UNIT |
|----------------------|-------------|----------------------------------------------------------------------------------------|------|------|------|------|
| Dark Current         | $I_D$       | $V_R=10\text{V}$                                                                       | —    | 0.1  | 2.0  | nA   |
| Forward Voltage      | $V_F$       | $I_F=1\text{mA}$                                                                       | —    | —    | 1.0  | V    |
| Capacitance          | $C_t$       | $V_R=0\text{V}, f=1\text{MHz}$                                                         | —    | 40   | —    | pF   |
|                      |             | $V_R=2.5\text{V}, f=1\text{MHz}$                                                       | —    | 20   | —    | pF   |
| Peak Wavelength      | $\lambda_P$ | —                                                                                      | —    | 850  | —    | nm   |
| Sensitivity          | $S$         | $V_R=2.5\text{V}, \lambda=940\text{nm}$                                                | 0.20 | 0.48 | —    | AWW  |
| Rise time, Fall time | $t_r/t_f$   | $V_R=2.5\text{V}, R_L=50\Omega, P_o=1\text{mW}, 10\text{-}90\%, \lambda=950\text{nm},$ | —    | 10   | —    | ns   |

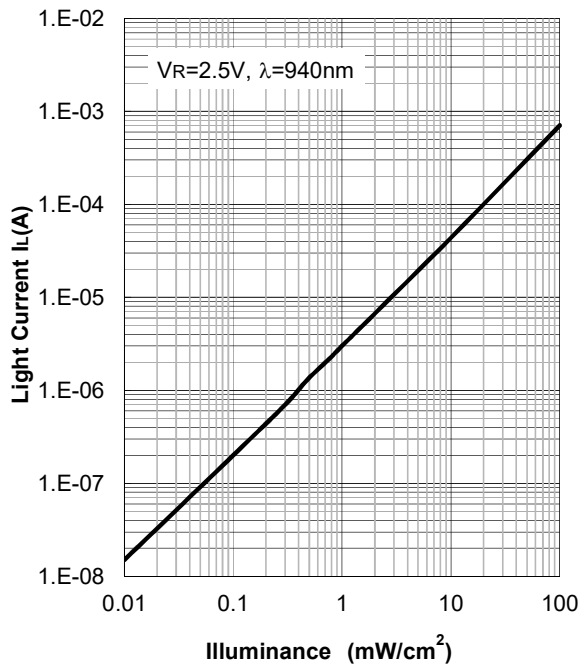
Note: In the Electro-Optical characteristics table, items that are showed only the typical value are not tested in manufacturing process.

## ■RESPONSE TEST CONDITION

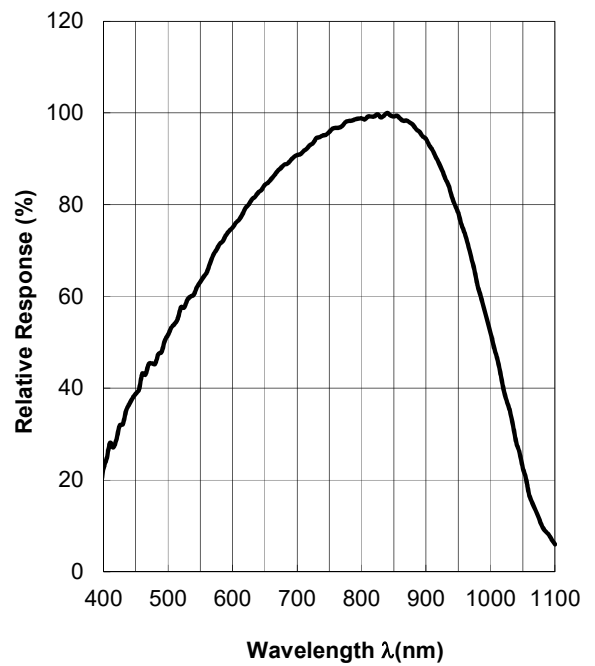


## ■ TYPICAL CHARACTERISTICS

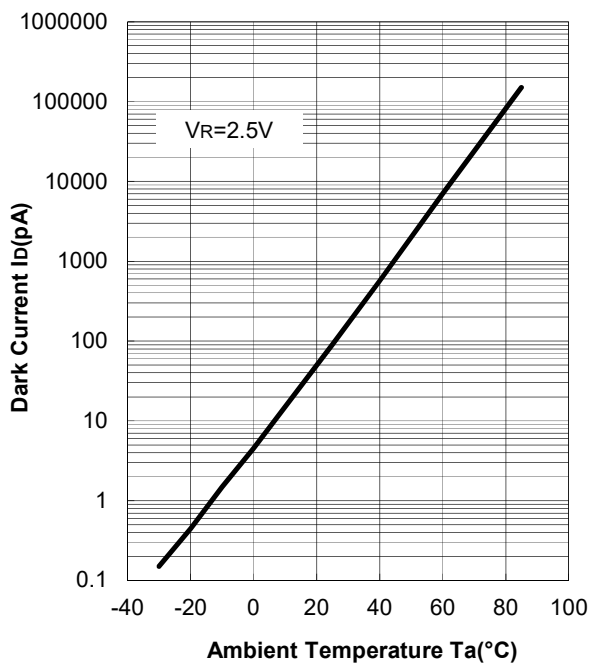
Light Current vs. Illuminance  
( $T_a=25^\circ\text{C}$ )



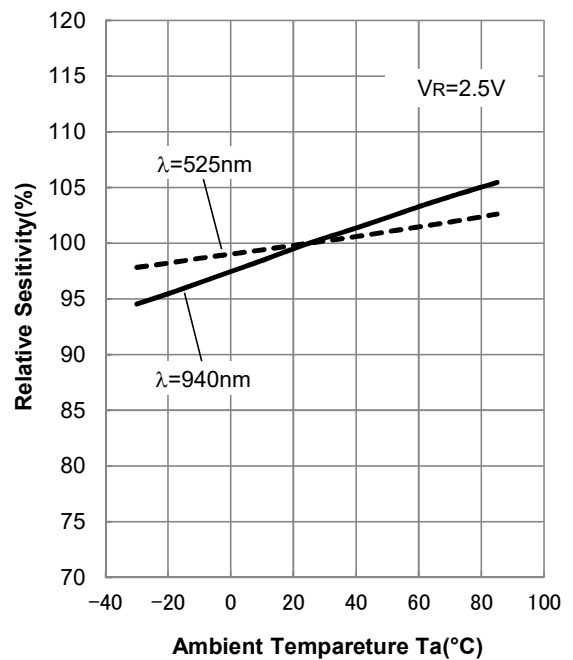
Spectral Response ( $T_a=25^\circ\text{C}$ )

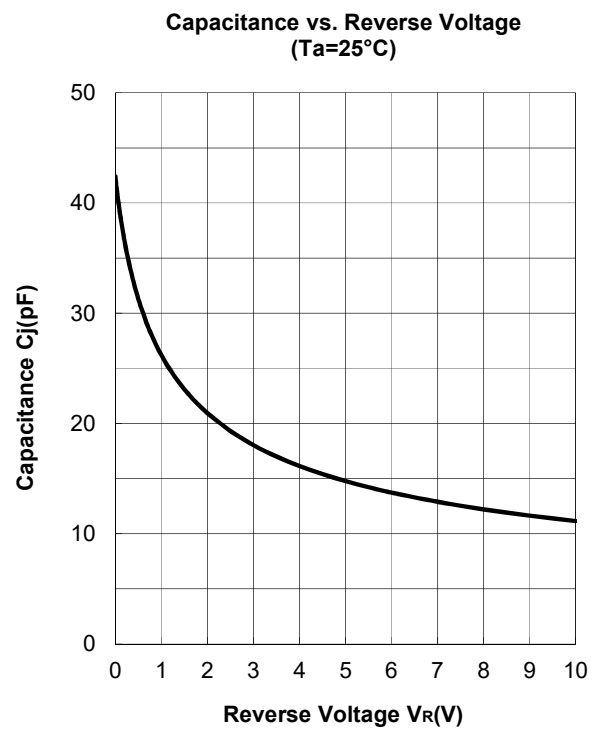
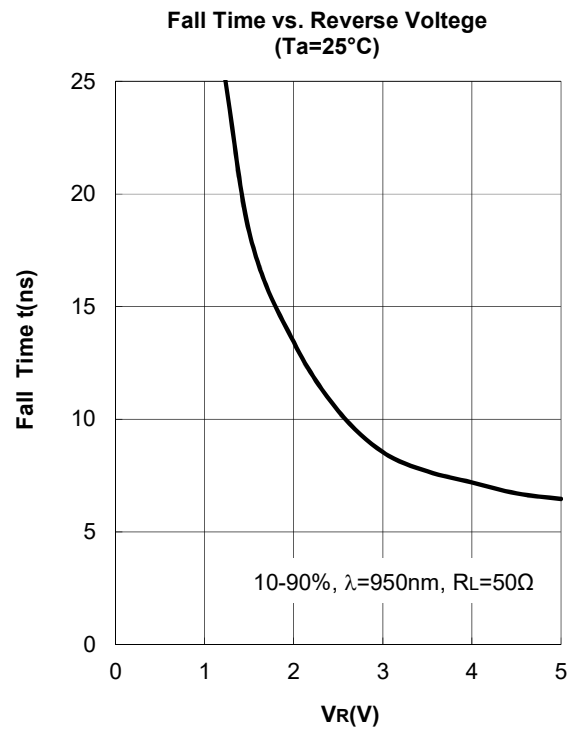
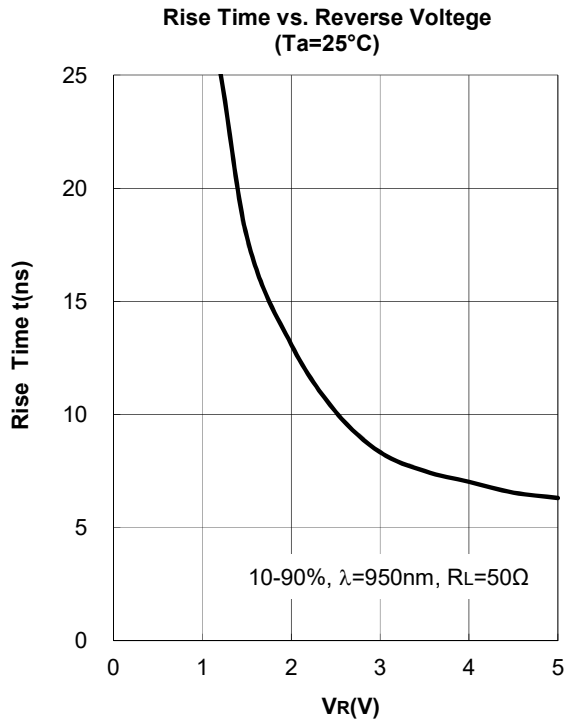


Dark Current vs. Temperature

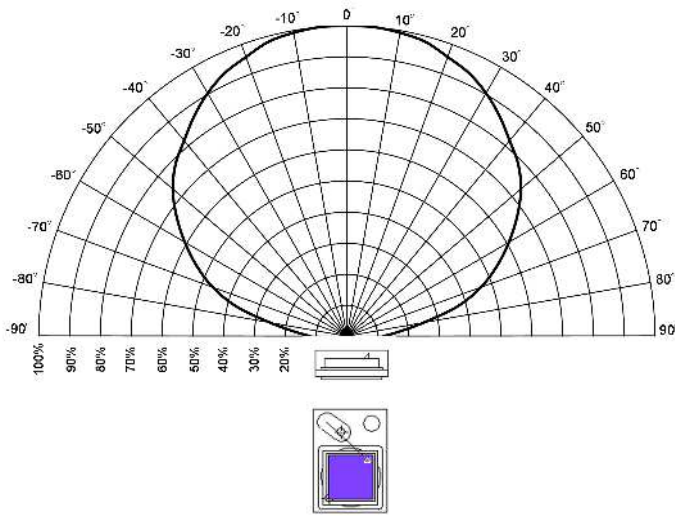


Relative Sensitivity vs. Temperature

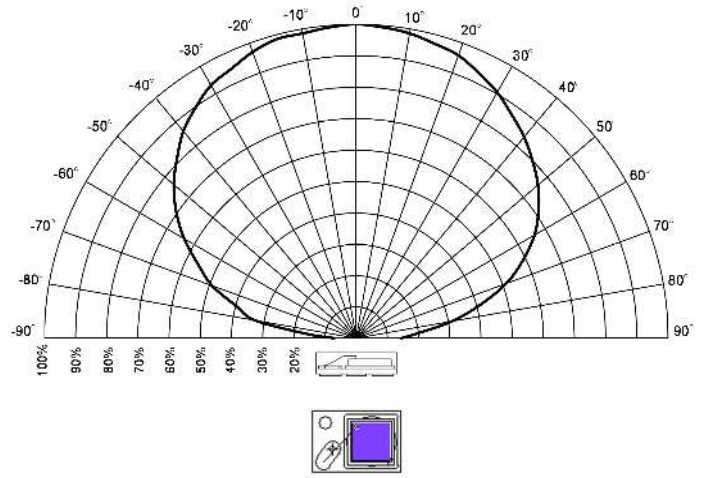




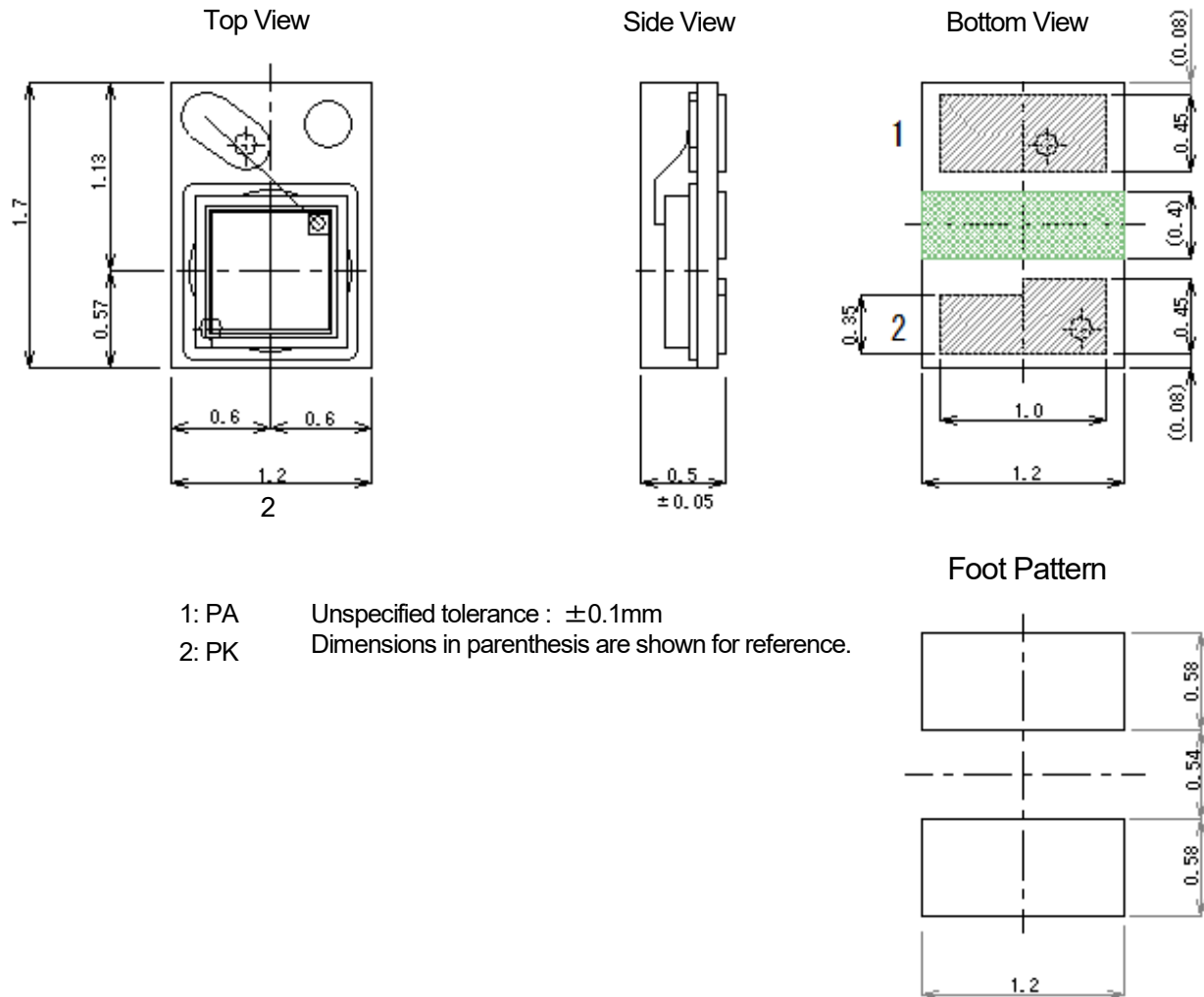
Directivity at Package direction X



Directivity at Package direction Y



■PACKAGE OUTLINE unit:mm

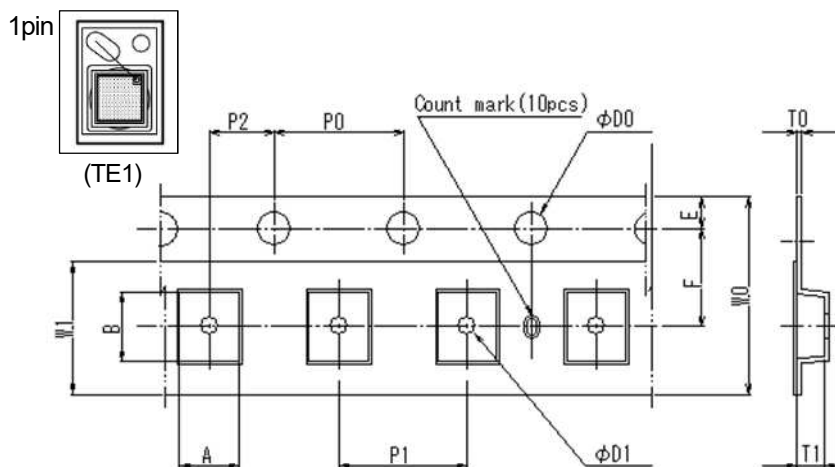


## ■ PACKING SPECIFICATION

PACKING DIMENSIONS UNIT : mm

Insert direction

Drawing direction 



| SYMBOL | DIMENSION      | REMARKS          |
|--------|----------------|------------------|
| A      | 1.50 ±0.05     | BOTTOM DIMENSION |
| B      | 2.00 ±0.05     | BOTTOM DIMENSION |
| D0     | φ1.50 +0.10/-0 |                  |
| D1     | φ0.50 ±0.05    |                  |
| E      | 1.75 ±0.10     |                  |
| F      | 3.50 ±0.05     |                  |
| P0     | 4.00 ±0.10     |                  |
| P1     | 4.00 ±0.10     |                  |
| P2     | 2.00 ±0.05     |                  |
| T0     | 0.20 ±0.05     |                  |
| T1     | 0.67 ±0.05     |                  |
| W0     | 8.00 ±0.10     |                  |
| W1     | 5.40 ±0.10     | THICKNESS 0.1MAX |

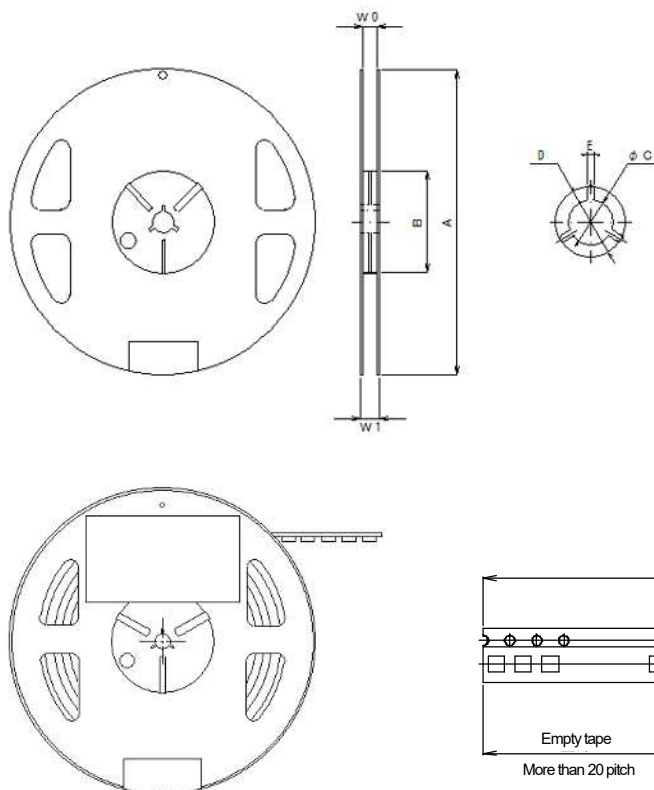
\* Carrier tape material : Polycarbonate(antistatic)  
Cover tape material : PET(antistatic)

## ■Taping Strength

There is a peel strength in the range of 0.2 to 0.7N when was peeled at a rate of 300mm per minute in opening angle 165 to 180° between the carrier tape and the cover tape.

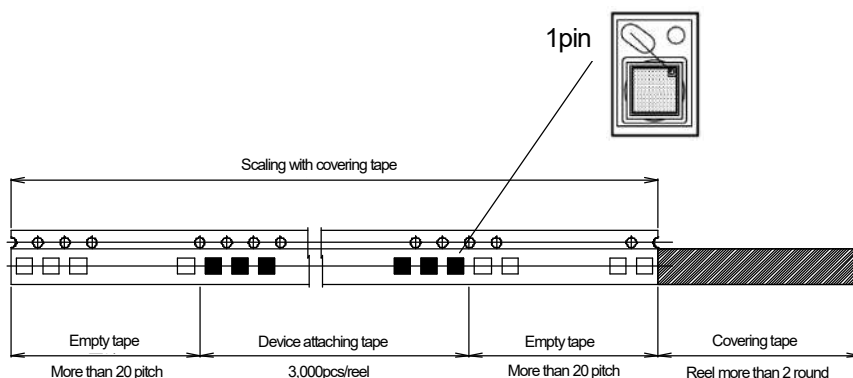
## ■Packaging

- 1) The taped products are to be rolled up on the taping reel as on the drawing.
- 2) Rolling up specification
  - 2-1) Start rolling : Carrier tape open space more than 20 Pieces.
  - 2-2) End of rolling : Carrier tape open space more than 20 Pieces, and 2 round of reel space at the cover tape only.
- 3) Taping quantity : 3,000 Pieces
- 4) Seal off after putting each reels in a damp proof bag with silica gel.



| SYMBOL | DIMENSION            | REMARKS         |
|--------|----------------------|-----------------|
| A      | $\phi 180.0 +0/-1.0$ |                 |
| B      | $\phi 60.0 +1.0/-0$  |                 |
| C      | $\phi 13.0 \pm 0.2$  |                 |
| D      | $\phi 21.0 \pm 0.8$  |                 |
| E      | $2.0 \pm 0.5$        |                 |
| W0     | $9.0 \pm 0.3$        | INNER DIMENSION |
| W1     | $11.4 \pm 1.0$       | OUTER DIMENSION |

\* Reel material : PS(antistatic)



## ■ RECOMMENDED MOUNTING METHOD

### NOTE

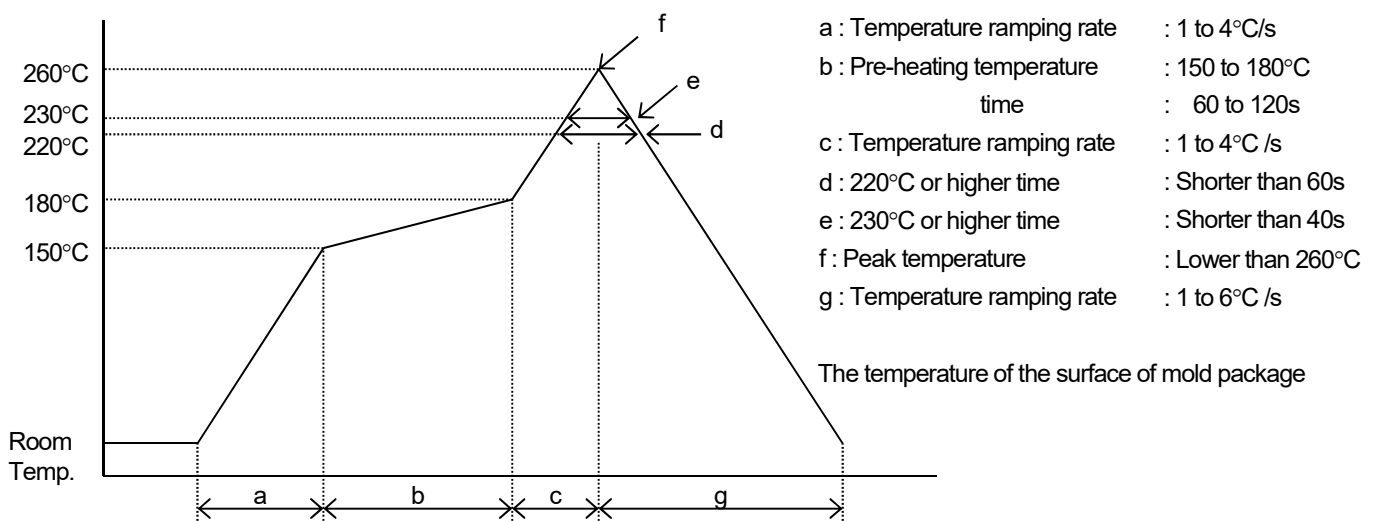
Mounting was evaluated with the following profiles in our company, so there was no problem.  
However, confirm mounting by the condition of your company beforehand.

The exposure of device under higher temperature may affect to the reliability of the products, it is recommended to complete soldering in the shortest time possible.

Mounting: Two Times soldering is allowed.

## ■ INFRARED REFLOW SOLDERING METHOD

Recommended reflow soldering procedure



(NOTE1) Using reflow furnace with short wave infrared radiation heater such as halogen lamp

Regarding temperature profile, please refer to those for reflow furnace.

In this case the resin surface temperature may become higher than lead terminals due to endothermic ally of black colored mold resin. Therefore, please avoid from direct exposure to mold resin.

(NOTE2) Other method

Such other methods of soldering as dipping the device into melted solder and vapor phase method (VPS) are not appropriate because the body of device will be heated rapidly. Therefore, these are not recommended to apply.

(NOTE3) The resin gets softened right after soldering, so, the following care has to be taken

Not to contact the lens surface to anything.

Not to dip the device into water or any solvents.

## ■ FLOE SOLDERING METHOD

Flow soldering is not possible.

## ■ IRON SOLDERING METHOD

Iron soldering is not possible.

**■ CLEANING**

Avoid washing the device after soldering by reflow method.

**■ IC STORAGE CONDITIONS AND ITS DURATION****(1) Temperature and humidity ranges**

|              |              |              |
|--------------|--------------|--------------|
| Pack Sealing | Temperature: | 5 to 40 [°C] |
|              | Humidity:    | 40 to 80 [%] |
| Pack Opening | Temperature: | 5 to 30 [°C] |
|              | Humidity:    | 40 to 70 [%] |

After opening the bag, solder products within 48h.

Avoid a dry environment below 40% because the products are easily damageable by the electrical discharge.

Store the products in the place where it does not create dew with the products due to a sudden change in temperature.

(2) When baking, place the reel vertically to avoid load to the side.

(3) Do not store the devices in corrosive-gas atmosphere.

(4) Do not store the devices in a dusty place.

(5) Do not expose the devices to direct rays of the sun.

(6) Do not allow external forces or loads to be applied to IC's.

(7) Be careful because affixed label on the reel might be peeled off when baking.

(8) The product is recommended to do the baking before using for the stability of the quality.

**■ BAKING**

In case of keeping expect above condition be sure to apply baking.

Baking method: Ta=60°C, 48 to 72h, One time baking is allowed

**■ STORAGE DURATION**

Within a year after delivering this device.

For the products stored longer than a year, confirm their terminals and solderability before they are used.

**■ APPLICATION NOTES**

When using the laser diode in the vicinity of  $\lambda=405\text{nm}$ , there is the restriction in terms of use.

Please be careful in the case of the use.

**■ MOISTURE SENSITIVITY LEVELS**

JEDEC : Level 5

**[ CAUTION ]**

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